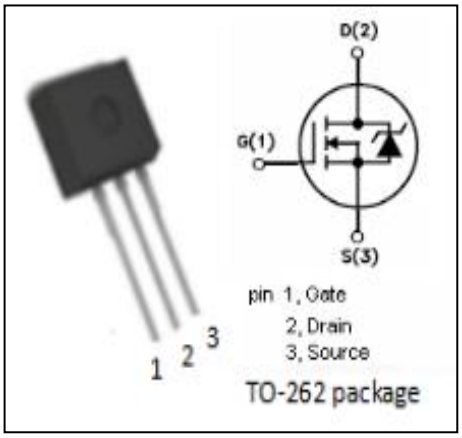
Isc N-Channel MOSFET Transistor IRF3808L

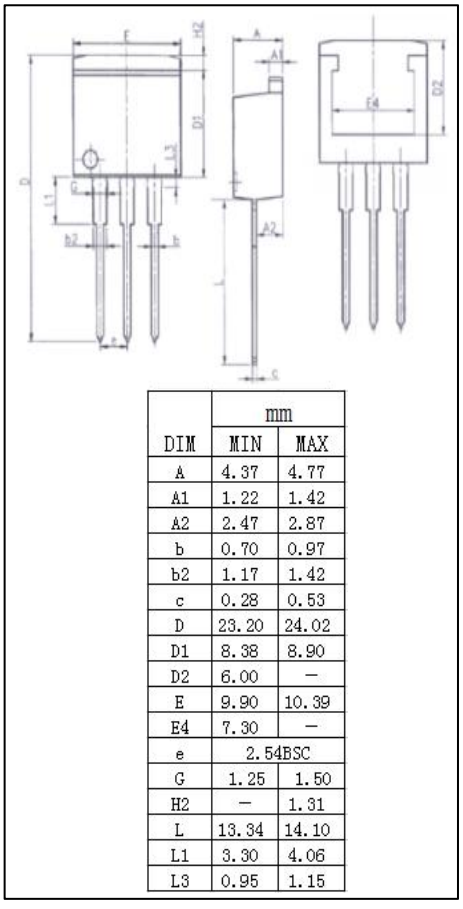
- **FEATURES**
- With To-262 package
- Low input capacitance and gate charge
- Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

- **APPLICATIONS**
- Switching applications



- **ABSOLUTE MAXIMUM RATINGS(T_a=25℃)**

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	75	V
V_{GSS}	Gate-Source Voltage	±20	V
I_D	Drain Current-Continuous Tc=25℃ Tc=100℃	106 75	A
I_{DM}	Drain Current-Single Pulsed	550	A
P_D	Total Dissipation @T_C=25℃	200	W
T_{ch}	Max. Operating Junction Temperature	175	℃
T_{stg}	Storage Temperature	-55~175	℃



DIM	mm MIN	MAX
A	4.37	4.77
A1	1.22	1.42
A2	2.47	2.87
b	0.70	0.97
b2	1.17	1.42
c	0.28	0.53
D	23.20	24.02
D1	8.38	8.90
D2	6.00	—
E	9.90	10.39
E4	7.30	—
e	2.54BSC	
G	1.25	1.50
H2	—	1.31
L	13.34	14.10
L1	3.30	4.06
L3	0.95	1.15

- **THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.75	℃/W
Rth(ch-a)	Channel-to-ambient thermal resistance	40	℃/W

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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	V_{GS}=0V; I_D= 0.25mA	75			V
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS}=V_{GS}; I_D=0.25mA	2.0		4.0	V
$R_{DS(on)}$	Drain-Source On-Resistance	V_{GS}= 10V; I_D=82A		5.9	7.0	mΩ
I_{GSS}	Gate-Source Leakage Current	V_{GS}= ±20V;V_{DS}= 0V			±0.2	μA
I_{DSS}	Drain-Source Leakage Current	V_{DS}=75V; V_{GS}= 0V;Tj=25℃ V_{DS}=60V; V_{GS}= 0V;Tj=150℃			20 250	μA
V_{SDF}	Diode forward voltage	I_{SD}=82A, V_{GS} = 0 Vs			1.3	V

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